NSN 5962-01-039-3439

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5.1.1	
Body Length:	
0.896 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
625.0 milliwatts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Signal data converter p/n 220-27121-101 fso	xm 80378
Features Provided:	
	lar and positive outputs and w/enable and programmable and programmed and wire-or outputs
nclosure Material:	
Ceramic and glass	
nclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Fransistor-transistor logic	
nput Circuit Pattern:	
10 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteris	tic:
5.5 volts power source	
Time Rating Per Chacteristic:	
65.00 nanoseconds propagation delay time	, low to high level output
Memory Device Type:	
Rom	
Test Data Document:	
96214-875418 drawing (this is the basic gov	verning drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;
excludes any specification, standard or othe	er document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:	
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0

